

- Inverter for motor drive
- AC and DC servo drive amplifier
- Uninterruptible power supply
  
- Low  $V_{CE(sat)}$  Trench-FS IGBT technology
- Maximum junction temperature 175
- Positive temperature coefficient
- Including fast & soft recovery anti-parallel FWD
- High short circuit capability(10us)

Collector-Emitter Breakdown Voltage	$V_{CE}$	1200	V
DC Collector Current, limited by $T_{jmax}$ $T_C= 25^{\circ}C$ $T_C= 100^{\circ}C$	$I_C$	50 25	A
Diode Forward Current, limited by $T_{jmax}$ $T_C= 25^{\circ}C$ $T_C= 100^{\circ}C$	$I_F$	50 25	A
Continuous Gate-Emitter Voltage	$V_{GE}$	$\pm 20$	V
Transient Gate-Emitter Voltage	$V_{GE}$	$\pm 30$	V
Turn off Safe Operating Area $V_{CE}$ 1200V, $T_j$ 150°C		100	A
Pulsed Collector Current, $V_{GE}=15V$ , tp limited by $T_{jmax}$	$I_{CM}$	100	A
Diode Pulsed Current, tp limited by $T_{jmax}$	$I_{Fpuls}$	100	A
Short Circuit Withstand Time, $V_{GE}= 15V$ , $V_{CC}=900V$ $V_{CEM}$ 1200V	$T_{sc}$	10	$\mu s$
Power Dissipation , $T_j=175^{\circ}C$ , $T_C=25^{\circ}C$	$P_{tot}$	326	W
Operating Junction Temperature	$T_j$	-40...+175	$^{\circ}C$
Storage Temperature	$T_s$	-55...+150	$^{\circ}C$
Soldering Temperature, wave soldering 1.6mm (0.063in.) from case for 10s		260	$^{\circ}C$



$T_j = 25$  unless otherwise specified

Collector-Emitter Breakdown Voltage	BV <sub>CES</sub>	$V_{GE}=0V, I_C=250\mu A$	1200		-	V
Gate Threshold Voltage	V <sub>GE(th)</sub>	$V_{GE}=V_{CE}, I_C=0.8mA$	5.1	5.8	6.4	V
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	$V_{GE}=15V, I_C=25A$ $T_j=25^\circ C,$ $T_j=125^\circ C$ $T_j=150^\circ C$		1.85 2.20 2.30	2.35	V
Zero Gate Voltage Collector Current	I <sub>CES</sub>	$V_{CE}=1200V, V_{GE}=0V$ $T_j=25^\circ C,$ $T_j=150^\circ C$			0.25 5.00	mA
Gate-Emitter Leakage Current	I <sub>GES</sub>	$V_{CE}=0V, V_{GE}=\pm 20V$			100	nA

Input Capacitance	C <sub>ies</sub>	$V_{CE}=25V, V_{GE}=0V,$ $f=1MHz$	-	1.45	-	nF
Reverse Transfer Capacitance	C <sub>res</sub>		-	0.05	-	
Gate Charge	Q <sub>G</sub>	$V_{CC}=960V, I_C=25A, V_{GE}=15V$	-	0.20	-	uC
Short Circuit Collector Current	I <sub>SC</sub>	$V_{GE}=15V, t_{sc} 10\mu s,$ $V_{CC}=900V, T_j 150^\circ C$	-	110	-	A

Operating Junction Temperature	T <sub>j</sub>	-40...+175	°C
Storage Temperature	T <sub>s</sub>	-55...+150	°C
Soldering Temperature, wave soldering 1.6mm (0.063in.) from case for 10s		260	°C



T<sub>j</sub>= 25 unless otherwise specified

Diode Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 25A T <sub>J</sub> = 25°C, T <sub>J</sub> = 125°C T <sub>J</sub> = 150°C		2.00 1.80 1.70		V

°C						
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>CC</sub> = 600V, I <sub>C</sub> =25A, V <sub>GE</sub> = -15v~15V, R <sub>g</sub> =18	-	158	-	ns
Rise Time	t <sub>r</sub>		-	32	-	ns
Turn-on Energy	E <sub>on</sub>		-	1.8	-	mJ
Turn-off Delay Time	t <sub>d(off)</sub>		-	331	-	ns
Fall Time	t <sub>f</sub>		-	83	-	ns
Turn-off Energy	E <sub>off</sub>		-	1.4	-	mJ
°C						
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>CC</sub> = 600V, I <sub>C</sub> =25A, V <sub>GE</sub> = -15v~15V, R <sub>g</sub> =18	-	172	-	ns
Rise Time	t <sub>r</sub>		-	45	-	ns
Turn-on Energy	E <sub>on</sub>		-	2.4	-	mJ
Turn-off Delay Time	t <sub>d(off)</sub>		-	154	-	ns
Fall Time	t <sub>f</sub>		-	212	-	ns
Turn-off Energy	E <sub>off</sub>		-	2.2	-	mJ
°C						
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>CC</sub> = 600V, I <sub>C</sub> =25A, V <sub>GE</sub> = -15v~15V, R <sub>g</sub> =18	-	190	-	ns
Rise Time	t <sub>r</sub>		-	48	-	ns
Turn-on Energy	E <sub>on</sub>		-	2.8	-	mJ
Turn-off Delay Time	t <sub>d(off)</sub>		-	165	-	ns
Fall Time	t <sub>f</sub>		-	230	-	ns
Turn-off Energy	E <sub>off</sub>		-	2.4	-	mJ



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°C						

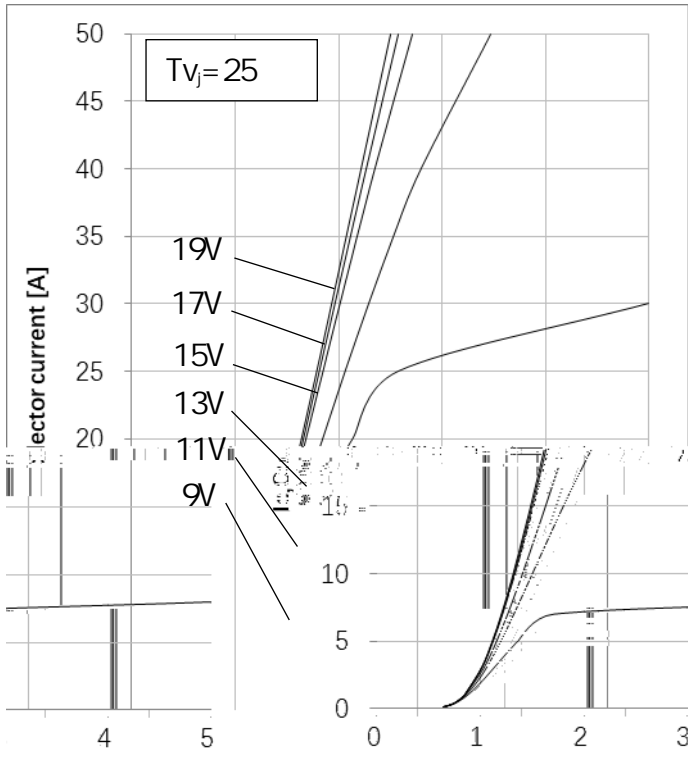


Fig1. Typical output characteristic

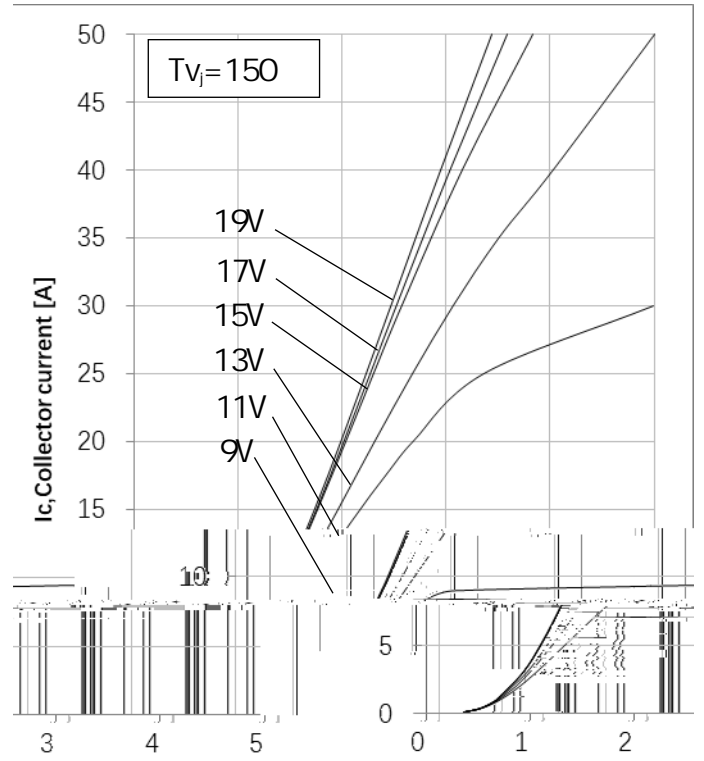


Fig2. Typical output characteristic

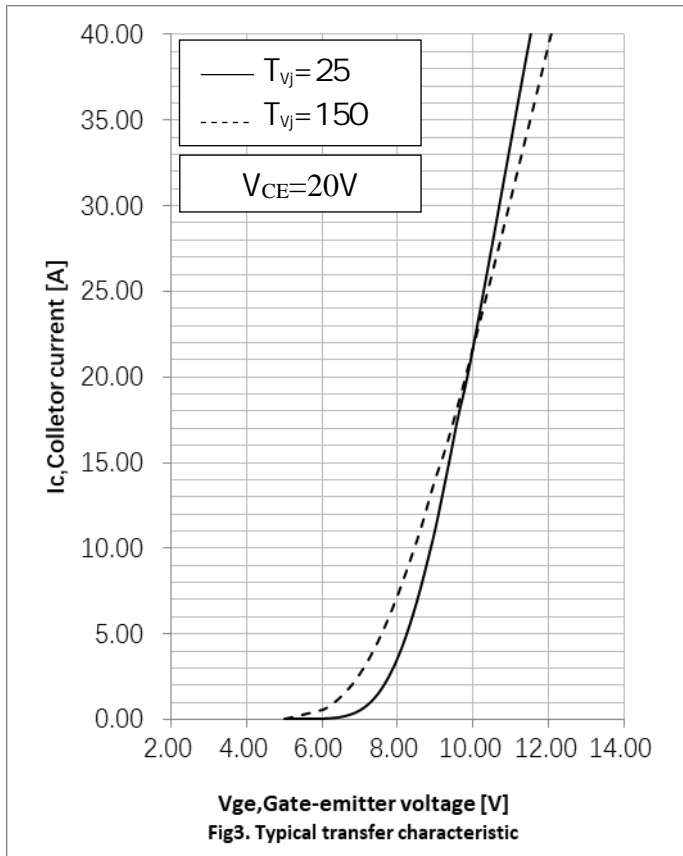


Fig3. Typical transfer characteristic

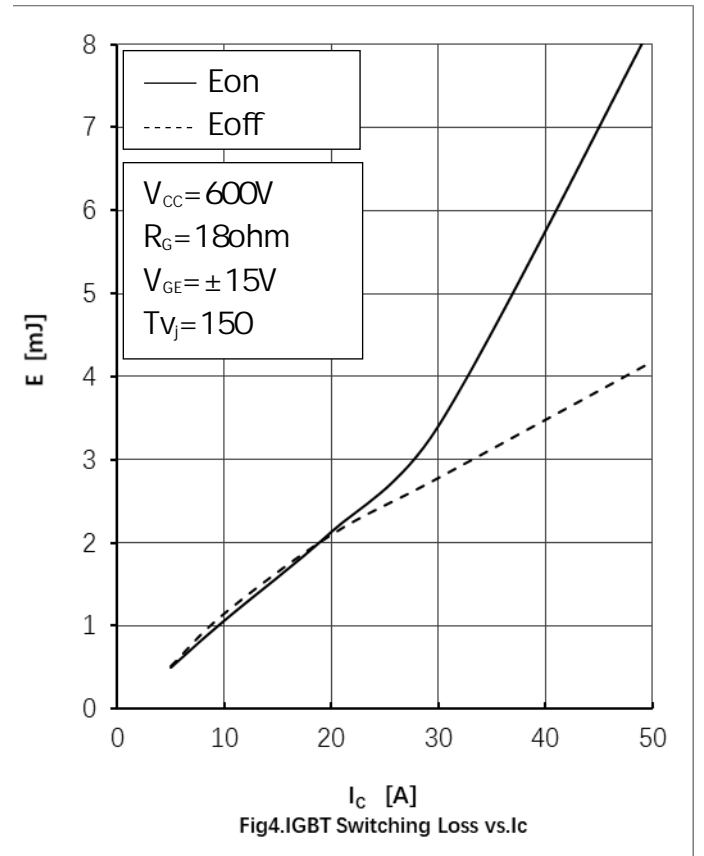
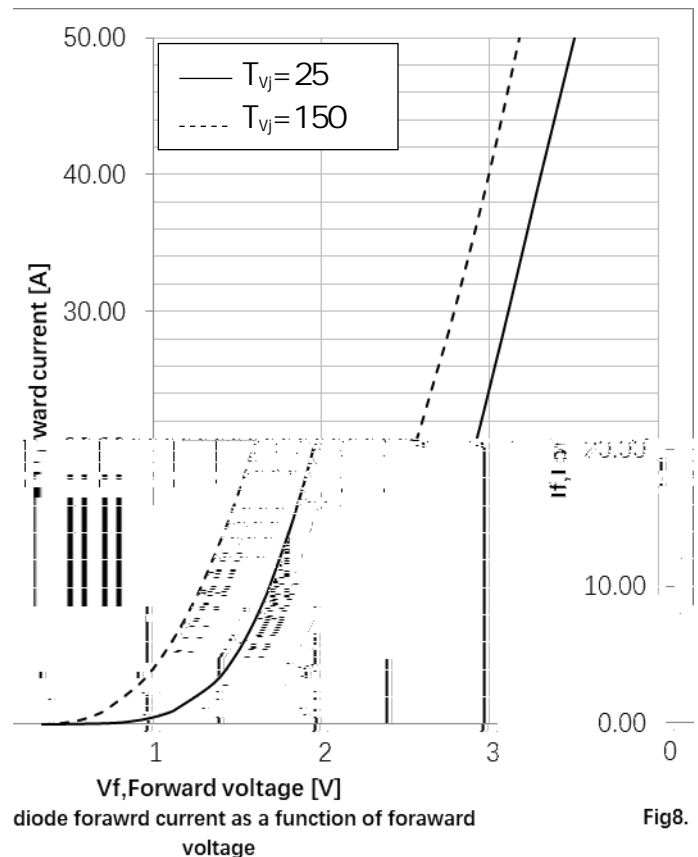
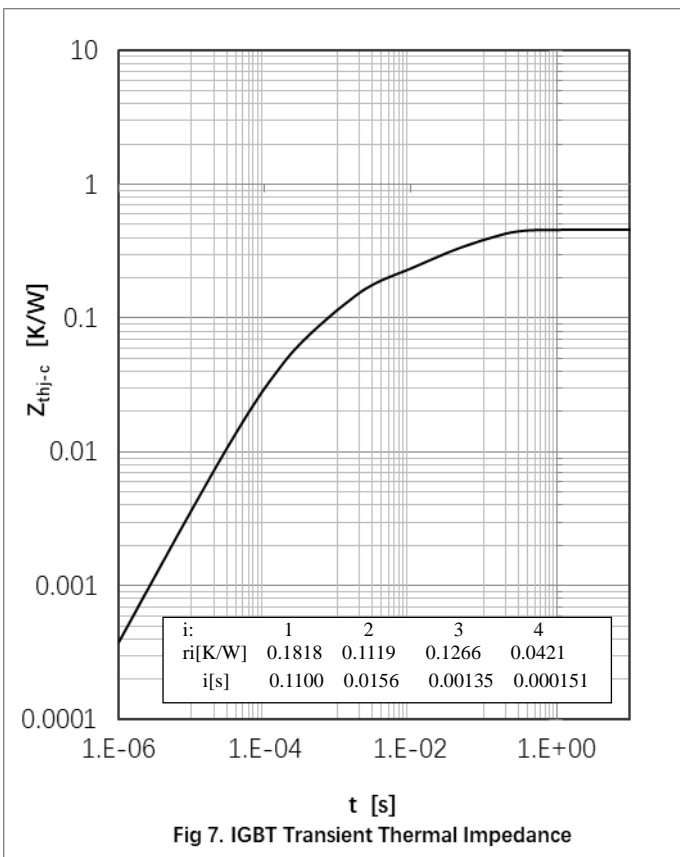
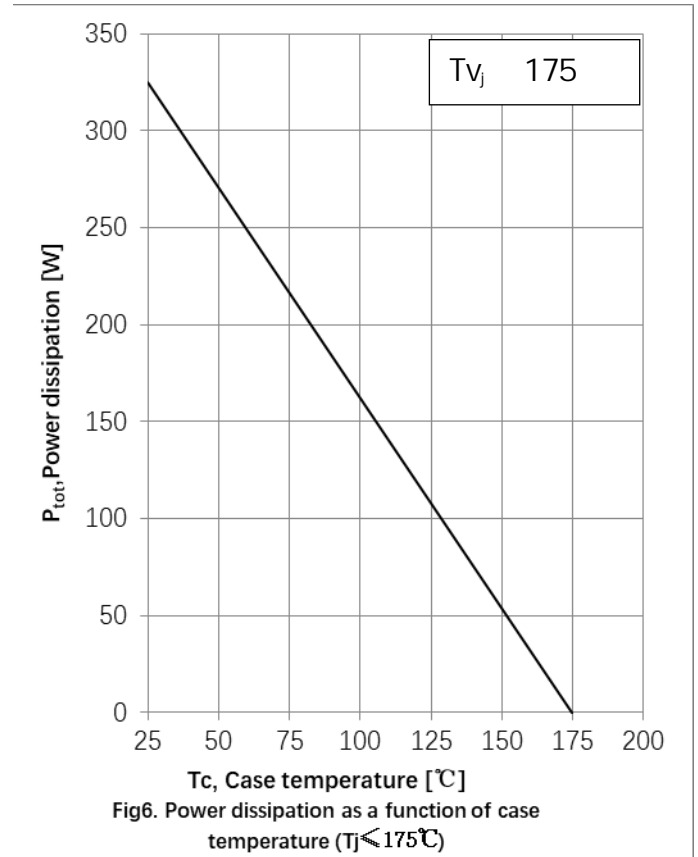
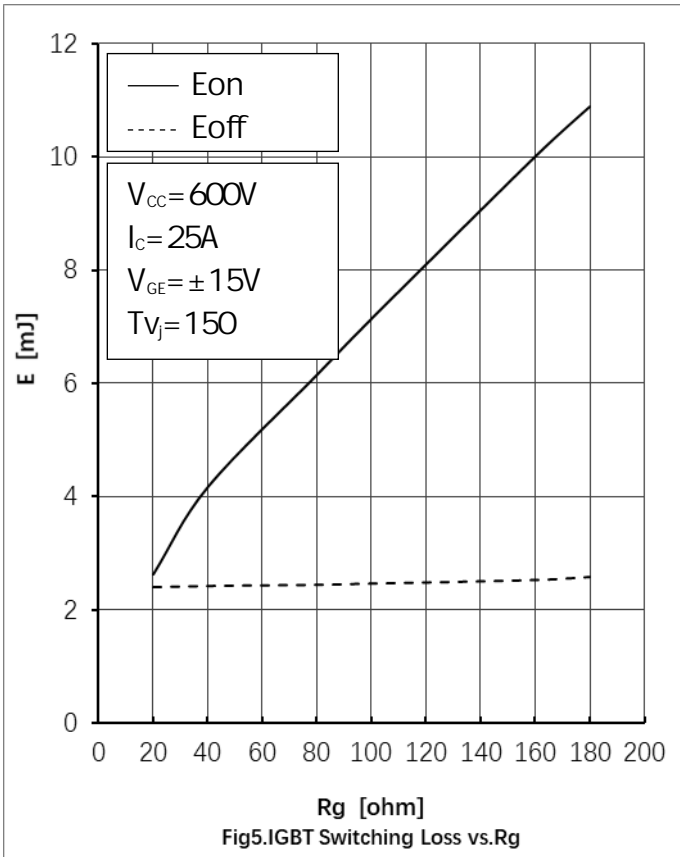


Fig4. IGBT Switching Loss vs. Ic



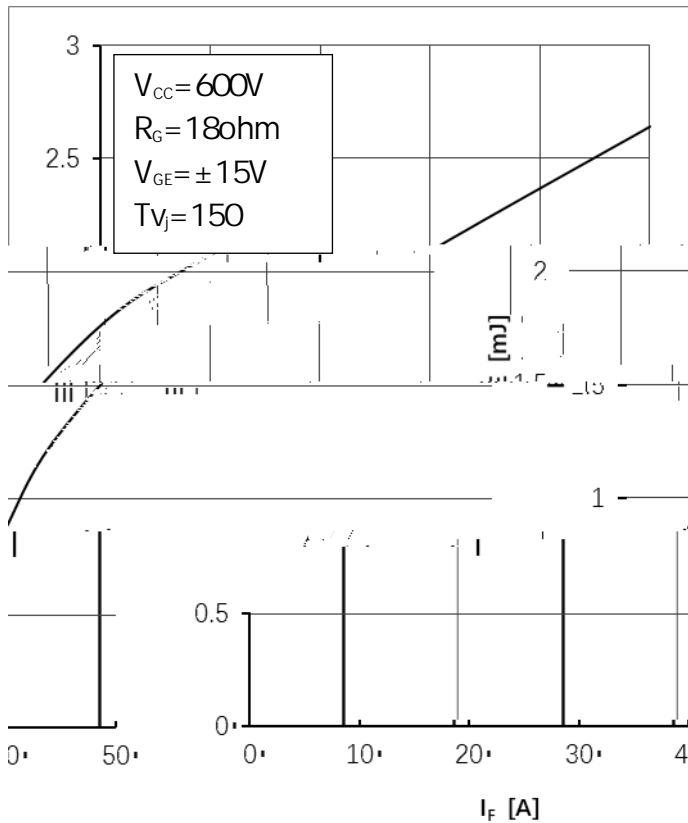


Fig9.Diode Switching Loss(Erec) vs.I<sub>F</sub>

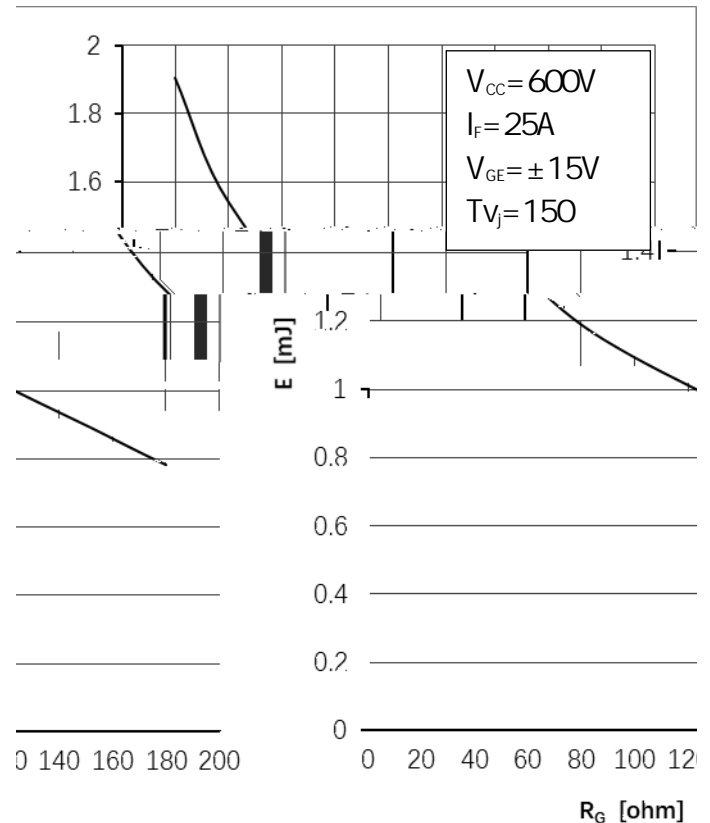


Fig10.Diode Switching Loss

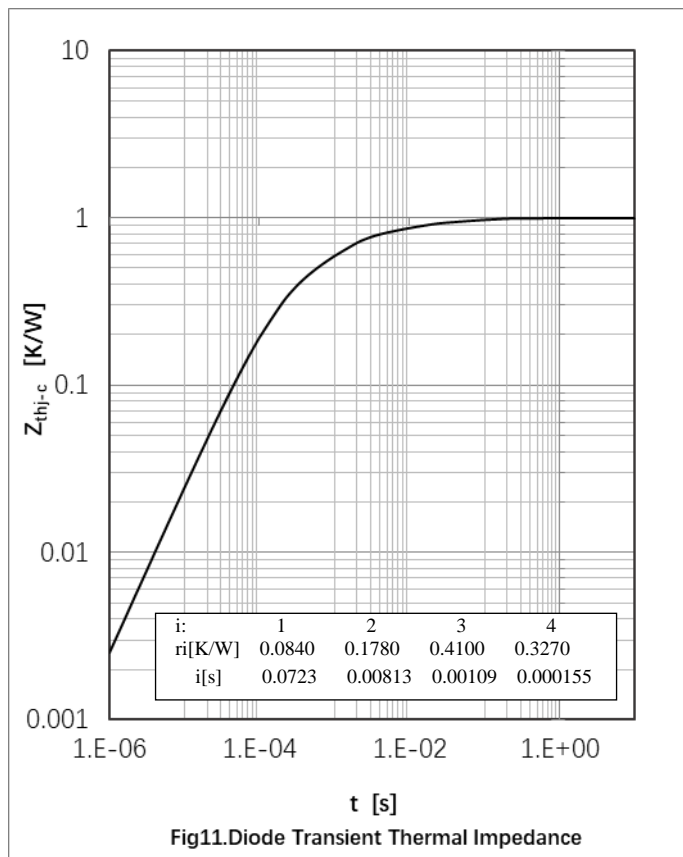


Fig11.Diode Transient Thermal Impedance

